

ST600K

LOW VOLTAGE NPN POWER TRANSISTOR

PRELIMINARY DATA

Features

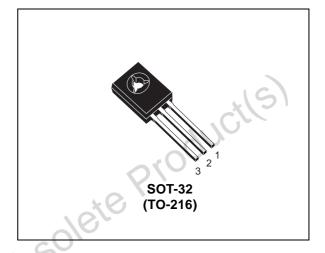
LOW SATURATION VOLTAGE

Applications

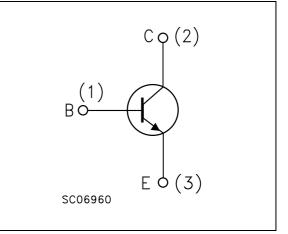
- SCANNING VELOCITY MODULATION IN CRT DISPLAYS
- MEDIUM POWER LINEAR AND SWITCHING APPLICATIONS

Description

The ST600K is manufactured by low voltage Epitaxial Base technology and it is housed in SOT-32 plastic package. The complementary PNP type is ST631K.



Internal Schematic Diagram



Order Codes

July 2005

Part Number	Marking	Package	Packing
ST600K	600K	SOT-32	TUBE

This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

Absolute Maximum Ratings 1

Symbol	Parameter		Value	Unit
V _{CBO}	Collector-Base Voltage (I _E = 0)		120	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	120	V	
V_{EBO}	Collector-Base Voltage (I _C = 0)		5	V
Ι _C	Collector Current		1	Α
I _{CM}	Collector Peak Current (t _P < 5ms)		2	Α
Ι _Β	Base Current		0.5	Α
I _{BM}	Base Peak Current (t _P < 5ms)		1	Α
P _{TOT}	Total dissipation at $T_c = 25^{\circ}C$		12.5	W
T _{STG}	Storage Temperature		-65 to 150	°C
Τ _J	Max. Operating Junction Temperature		150	°C
able 2.	Thermal Data	1ete		

Table 1. **Absolute Maximum Rating**

Table 2. Thermal Data

Symbol	Parameter	<u> </u>	Value	Unit
R _{thJ-case} R _{thJ-amb}	Thermal Resistance Junction-Case	Max Max	10 100	°C/W °C/W
	product(s)			
Obsol	ster			

2 Electrical Characteristics

Table 3.	Electrical	Characteristics	$(T_{CASF} = 25)$	5°C; unless	otherwise specified)
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Symbol	Parameter	Test Cond	itions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-off Current $(I_E = 0)$	V _{CB} = 50V				1	μA
I _{EBO}	Emitter Cut-off Current $(I_{C} = 0)$	$V_{EB} = 4V$				1	μA
V _{(BR)CBO} Note: 1	Collector-Base Breakdown Voltage (I _E = 0)	I _C = 10μA		120		10	V
V _{(BR)CEO} Note: 1	Collector-Emitter Breakdown Voltage (I _C = 0)	I _E = 1 mA		120	11	CI	v
V _{(BR)EBO} Note: 1	Collector-Emitter Breakdown Voltage (I _B = 0)	I _C = 10 mA		120	00,	1	V
V _{CE(sat)} Note: 1	Collector-Emitter Saturation Voltage	I _C = 500 mA	I _B = 50 mA			0.5	V
V _{BE(sat)} Note: 1	Base-Emitter Saturation Voltage	I _C = 500 mA	I _B = 50 mA			1.2	V
h _{FE} Note: 1	DC Current Gain	$I_{\rm C} = 100 \text{ mA}$ $I_{\rm C} = 500 \text{ mA}$	V _{CE} = 5 V V _{CE} = 5 V	120 50		280	
C _{CBO}	Collector-Base Capacitance $(I_B = 0)$	V _{CB} = 10 V	f=1MHz		40		pF
	INDUCTIVE LOAD	I _C = 500 mA	$V_{CC} = 12V$				
t _{on}	Turn-On Time	I _{B1} = - I _{B2} =50 mA	t _p = 20μs		100		ns
t _{off}	Turn-Off Time				500		ns
t _s	Storage Time				800		ns

Note: 1 Pulsed duration = $300 \ \mu s$, duty cycle $\le 1.5\%$.



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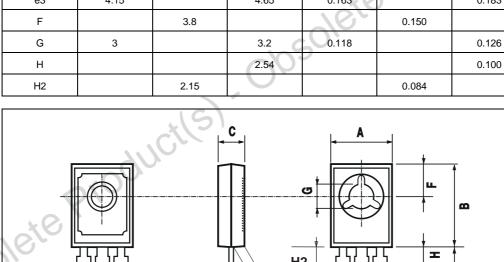
3 Package Mechanical Data

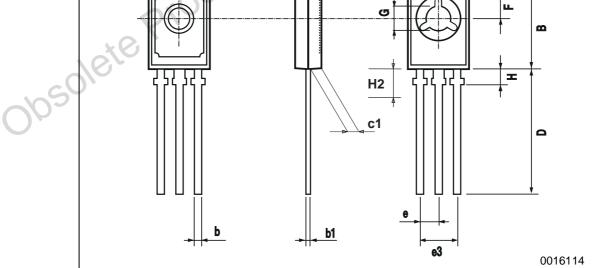
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

obsolete Product(s). Obsolete Product(s)



DIM.	mm			inch			
Dim.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	7.4		7.8	0.291		0.307	
В	10.5		10.8	0.413		0.445	
b	0.7		0.9	0.028		0.035	
b1	0.49		0.75	0.019		0.030	
С	2.4		2.7	0.040		0.106	
c1	1.0		1.3	0.039		0.050	
D	15.4		16.0	0.606	~0	0.629	
е		2.2			0.087		
e3	4.15		4.65	0.163	,	0.183	
F		3.8		10,	0.150		
G	3		3.2	0.118		0.126	
н			2.54			0.100	
H2		2.15	U.		0.084	T	







4 Revision History

Date	Revision	Changes
26-Jul-2005	1	Initial release.

obsolete Product(s). Obsolete Product(s)



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